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3D Crumpled Ultrathin 1T MoS₂ for Inkjet Printing of Mg-Ion Asymmetric Micro-supercapacitors

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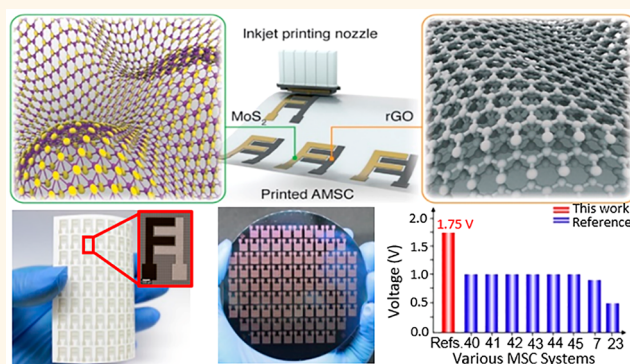
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ABSTRACT: Metallic molybdenum disulfide (MoS₂), *e.g.*, 1T phase, is touted as a highly promising material for energy storage that already displays a great capacitive performance. However, due to its tendency to aggregate and restack, it remains a formidable challenge to assemble a high-performance electrode without scrambling the intrinsic structure. Here, we report an electrohydrodynamic-assisted fabrication of 3D crumpled MoS₂ (c-MoS₂) and its formation of an additive-free stable ink for scalable inkjet printing. The 3D c-MoS₂ powders exhibited a high concentration of metallic 1T phase and an ultrathin structure. The aggregation-resistant properties of the 3D crumpled particles endow the electrodes with open space for electrolyte ion transport. Importantly, we experimentally discovered and theoretically validated that 3D 1T c-MoS₂ enables an extended electrochemical stable working potential range and enhanced capacitive performance in a bivalent magnesium-ion aqueous electrolyte. With reduced graphene oxide (rGO) as the positive electrode material, we inkjet-printed 96 rigid asymmetric micro-supercapacitors (AMSCs) on a 4-in. Si/SiO₂ wafer and 100 flexible AMSCs on photo paper. These AMSCs exhibited a wide stable working voltage of 1.75 V and excellent capacitance retention of 96% over 20 000 cycles for a single device. Our work highlights the promise of 3D layered materials as well-dispersed functional materials for large-scale printed flexible energy storage devices.

KEYWORDS: supercapacitors, MoS₂, printing technique, Mg-ion, microdevice



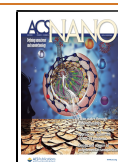
Recent advancements in portable electronics and emerging interest in wearable miniaturized devices, on-body medical monitors, and the Internet of Things (IoT) nodes have propelled the needs for miniaturized portable energy storage devices.^{1–4} To enable direct integration with functional electronic/sensing units at scale, small-size and discrete energy storage devices need to be reasonably thin, mechanically robust, electrochemically durable, and dynamically flexible in nature. However, feasible designs in device architecture and viable manufacturing means of fabricating miniaturized energy storage components, such as micro-supercapacitors (MSCs), for energy delivery or harvesting with high power and energy capabilities remain a significant challenge.^{5,6} An array of cost-effective manufacturing processes for MSCs needs to address the pressing needs. Notable innovations of fabricating MSCs include laser scribing/ablation,^{7,8} electrochemical deposition,⁹ vacuum filtration,^{10,11} and spray-coating.¹² These pioneering demon-

strations, while promising, cannot precisely “print out” elaborated designs of micropatterns with high resolution and excellent reliability, especially when more than one type of active material needs to be deposited, which is a key prerequisite for expanded stable electrochemical potential windows through the deployment of asymmetric MSCs (AMSCs).¹³ Meanwhile, inkjet printing offers a promising contactless deposition strategy to create complex layouts of multifunctional materials with well-defined features and

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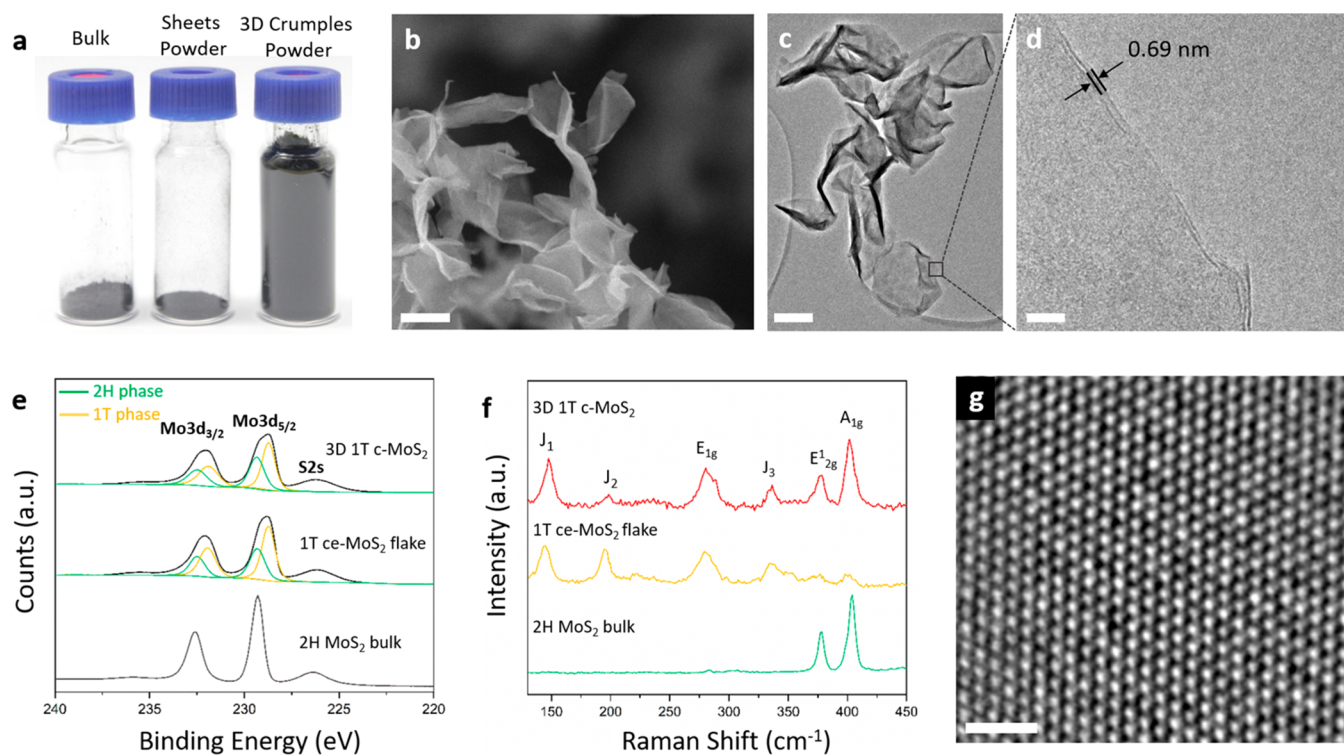


Figure 1. Preparation and characterization of a 3D c-MoS₂ dispersion with a high concentration of 1T phase. (a) Photograph featuring the transition from (left) bulk MoS₂ powder, (middle) ce-MoS₂ sheets, and (right) the solid 3D 1T c-MoS₂ powder in vials with the same weight for comparison. It is apparent that crumpling of planar 1T ce-MoS₂ sheets into 3D 1T c-MoS₂ results in a significant volumetric expansion. (b) SEM image shows the morphology of as-printed 3D 1T c-MoS₂. Scale bar: 200 nm. (c) Low-magnification TEM image of a single 3D 1T c-MoS₂. Scale bar: 200 nm. (d) Magnified TEM image of a 3D 1T c-MoS₂ edge. (e, f) Representative high-resolution XPS spectra of the Mo 3d peaks and Raman spectra for 3D 1T c-MoS₂, ce-1T MoS₂ flake, and 2H MoS₂ bulk, respectively. (g) HRTEM analysis reveals the preservation of the octahedral arrangement of the 3D 1T c-MoS₂.

morphologies, over a myriad of substrates in a high-throughput fashion.^{14–18}

Inkjet printing can provide an attractive route to low-cost fabrication of MSCs with multifunctional active materials and high resolution. The new class of two-dimensional materials, including graphene,^{19–21} transition-metal dichalcogenides (TMDs),^{14,16} and MXenes,^{22,23} shows great promise for use in inkjet-printed flexible electronics, because their atomic thickness allows for maximum active surface area, unique electronic properties, and mechanical flexibility. As a promising TMD for energy storage devices,^{24–26} 1T metallic molybdenum disulfide (MoS₂) has been investigated extensively due to its unique layered structure, good electrochemical performance, and the earth abundance of bulk MoS₂ as a mineral.^{27–29} Typically, the 1T phase exhibits significantly enhanced hydrophilicity and an electrical conductivity at least 5 orders of magnitude higher than that of 2H-MoS₂, which result in an extreme high volumetric capacitance of ~ 700 F cm⁻³ in an aqueous electrolyte.²⁴ Thus, 1T MoS₂ could be an ideal material to fabricate high-performance MSCs. However, just like other typical 2D materials, layered MoS₂ sheets tend to restack through out-of-plane van der Waals interactions, which not only decreases the active surface area but also hinders efficient electrolyte ion diffusion, resulting in a rapid decay of electrochemical performance. Converting the ultrathin 2D materials to 3D atomic thick building blocks without sacrificing the intrinsic atomic thickness for inkjet printing, MSCs can be a promising strategy to solve the restacking issue.

Here, we report an electrohydrodynamic-assisted method (electrospray) to prepare a 1T phase dominated by 3D crumpled MoS₂ (c-MoS₂) as a powder and its stable ink formation for inkjet printing of MSCs with fine resolution. By using a volatile solvent for the MoS₂ dispersion and multijetting mode, the extremely fast solvent evaporation and ink solidification of the electrospray process guarantee a high proportion of the 1T phase and an ultrathin structure of the obtained 3D c-MoS₂ powder. After dispersion in an optimized mixed binary alcohol solvent, MoS₂ ink is prepared without introducing any obvious phase transformation of the 1T MoS₂, often caused by temperature variation or chemical treatment. AMSCs made of 3D 1T c-MoS₂ inks and reduced graphene oxide (rGO) wrinkled flakes can be precisely printed onto large substrates with an interdigitated pattern. The inkjet printing of 96 AMSCs on a 4 in. Si/SiO₂ wafer and 100 flexible AMSCs on a 10 cm × 10 cm EPSON photopaper demonstrates the scalability and high resolution of the inkjet printing technique. A single printed AMSC can deliver a wide stable working voltage of 1.75 V and excellent capacitance retention of 96% over 20 000 cycles, an areal energy density of 3.85 μWh cm⁻², and a maximum power density of 12.6 mW cm⁻² in a Mg-ion aqueous electrolyte.

RESULTS AND DISCUSSION

Three-dimensional 1T c-MoS₂ powders were obtained through the electrospray of chemically exfoliated (ce-) MoS₂ flakes, which were synthesized by a modified Li-intercalation process.³⁰ Based on the photograph (Supplementary Figure

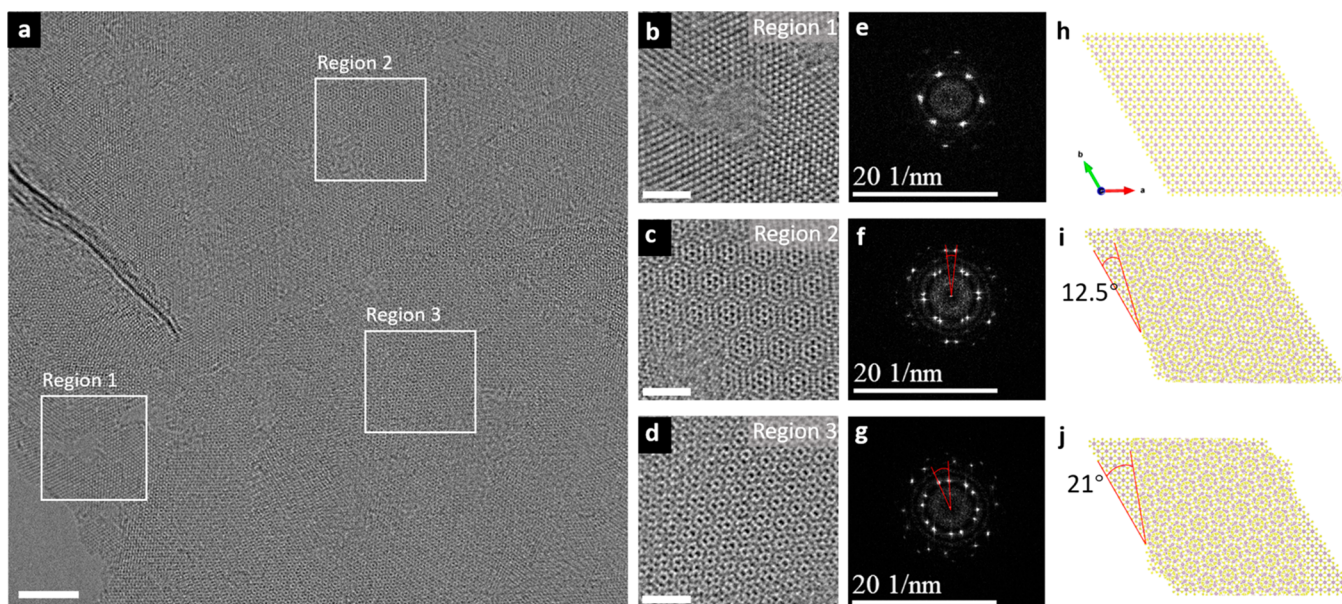


Figure 2. HRTEM characterization and fast Fourier transform (FFT) patterns of 3D c-MoS₂. (a) HRTEM image of 3D 1T c-MoS₂ containing mostly mono- (region 1) to bilayer (regions 2 and 3) MoS₂ sheets. The octahedral arrangement of the Mo atoms in region 1, corresponding to the 1T phase, is clearly shown in the (b) selected close-up view of region 1, (e) the FFT pattern, and (h) single-layer MoS₂ in the atomic model. Meanwhile, the bilayer regions exhibit two sets of twist angles (12.5° vs 21°) and the formation of two distinctive moiré patterns as confirmed by the (c, d) close-up views and (f, g) FFT patterns along with (i, j) computer-generated atomic models.

S1a inset) taken under red laser irradiation, the ce-MoS₂ flakes dispersed in isopropyl alcohol (IPA), a low-viscosity solvent, were ejected simultaneously from all directions of the capillary circumference and formed into a multiple cone with distinct streams of mist, known as multijet mode.³¹ With the intense electrical shear stress at high applied electric field (1.35 kV/cm) and highly divergent jetting under the multijet mode, the size of the droplet generated can be nearly monodisperse and much smaller than that produced from single cone jet or Taylor cone jet mode.³² The detailed electrospray deposition process of 3D 1T c-MoS₂ from a ce-MoS₂ dispersion is illustrated in the schematic in Supplementary Figure S1b and explained in Supplementary Note 1. Upon solvent evaporation-induced volumetric shrinkage, the charge density residing on the surface of the charged droplets drastically increases. After exceeding the Rayleigh limit,³³ droplets fission into numerous smaller ones, which only contain single MoS₂ flakes. The charged droplet fission is beneficial to form ultrafine and monodisperse nanoparticles, thus avoiding the aggregation of the 2D nanoflakes. Due to the continuous evaporation of solvent, the droplets keep shrinking and even start to solidify, which results in the crumpling of the MoS₂ flakes. The photograph in Figure 1a features a density comparison of bulk MoS₂, ce-MoS₂ flakes, and 3D 1T c-MoS₂ powders in glass vials with the same weight (4 mg), which demonstrates the significant volume expansion after the electrohydrodynamic-assisted fabrication process. The scanning electron microscope (SEM) and transmission electron microscope (TEM) images of the as-deposited flakes (Figure 1b,c) reveal the uniform dispersed and hierarchically porous yet thin folded walls. The high-resolution TEM (HRTEM) observation in Figure 1d demonstrates the bilayer thickness of 3D 1T c-MoS₂. The high electric field induced multijet mode is one of the crucial parameters to achieve the highly crumpled and monodispersed MoS₂. Supplementary Figure S2 demonstrates that the MoS₂

flakes significantly begin to stack and aggregate when the applied electric field voltage is decreased.

As exhibited in Figure 1e,f, X-ray photoelectron spectroscopy (XPS) and Raman spectroscopy were used to characterize the chemical states of the as-prepared 3D c-MoS₂. Deconvolution of the Mo 3d region of the 3D 1T c-MoS₂ indicates that the 1T phase ratio is 62.7%, an only minor decrease from the 64.6% of the ce-MoS₂ precursors. Following the same trend as XPS, the Raman spectra of the 3D 1T c-MoS₂ also exhibit characteristic peaks mainly to the 1T phase, including typical peaks of J₁, J₂, and J₃ modes at 221, 281, and 330 cm⁻¹ and in tandem with 377 and 402 cm⁻¹ assigned to the E_{2g}¹ and A_{1g} modes of 2H phase. A strong Raman band at 148 cm⁻¹ of 3D 1T c-MoS₂ can be attributed to the Mo–Mo stretching vibrations in 1T MoS₂. The other signature Raman shifts of c-MoS₂ at ~221, 281, and 330 cm⁻¹ are also associated with the phonon modes in 1T MoS₂, which matches well with the ce-MoS₂ flake. The high 1T phase concentration was also verified by HRTEM, as shown in Figure 1g. The stacking sequence for 3D 1T c-MoS₂ follows AbC stacking, where the S atoms in the upper and lower planes are offset from each other and the Mo atoms occupy the octahedral holes of the S layer. Due to the stark contrast in atomic numbers, signals derived from S atoms in the monolayered 1T MoS₂ are relatively weak compared to the Mo atoms. Thus, the 3D 1T c-MoS₂ exhibits a hexagonal lattice signature, as can be seen in Figure 1g and Supplementary Figure S4d.

Figure 2a shows the HRTEM of the edge of a single 3D 1T c-MoS₂. Indeed, the edges of 3D 1T c-MoS₂ are mostly monolayer (Figure 2b, region 1) and exhibit a single set of 6-fold symmetry spots from the fast Fourier transform (FFT) pattern (Figure 2e), corroborating the representative hexagonal atomic structure of single-layer 1T MoS₂ (Figure 2h). Meanwhile, as suggested in Figure 2c,d, HRTEM images of region 2 and region 3 comprise two different moiré patterns with different periodicities and misorientations. Moiré patterns

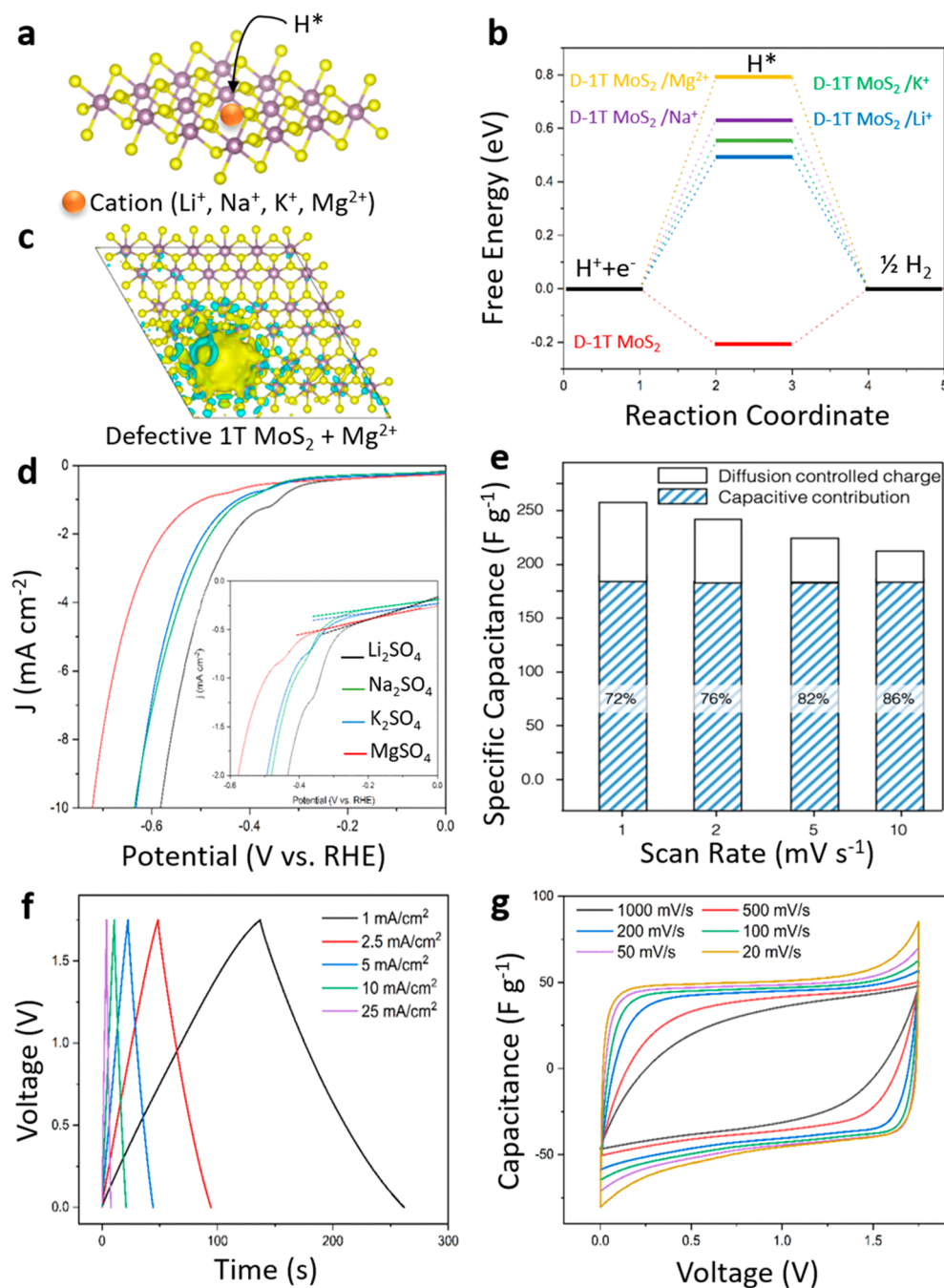


Figure 3. Theoretical insights and electrochemical characterization of 3D 1T *c*-MoS₂. (a) Schematic of the perspective view of defective 1T MoS₂ where adsorption of mono- and divalent ions takes place. (b) Free energy *versus* the reaction coordinate of the HER. ΔG_{H} is used as a descriptor for correlating the DFT prediction with experimental measurements for the HER. (c) DFT modeling reveals a surge in local electron density around the binding sites of the divalent Mg ions. (d) LSV curves of the 3D 1T *c*-MoS₂ electrode measured in different neutral electrolytes, including 0.5 M Li₂SO₄, 0.5 M Na₂SO₄, 0.5 M K₂SO₄, and 1.0 M MgSO₄. Inset shows the onset potentials for the HER. Incorporation of divalent Mg ions gives rise to significantly increased overpotential and thus the stable potential window. (e) Capacitive and diffusion-controlled contributions of the 3D 1T *c*-MoS₂ electrode at different scan rates. (f, g) GCD and CV curves of a 3D 1T *c*-MoS₂//rGO asymmetric supercapacitor at different current densities and scan rates, representatively.

typically are taken as a hallmark of enabling the stacking between monolayer crystals with disproportionate lattices and arbitrary mutual rotation. The result is an extended periodicity that emerges from the local atomic registry as shown on the basal plane of 3D 1T *c*-MoS₂. The corresponding FFT patterns contain double sets of 6-fold symmetry diffraction spots (Figure 2f,g). According to the measurement of the splitting spots in the FFT patterns (Supplementary Figure S3), the

moiré patterns in these two regions exhibit twist angles of 12.5° and 21°, confirmed by the FFT (Figure 2f,g) and simulated atomic models (Figure 2i,j). Moiré patterns that typically arise in bilayer stacking with small misalignment between adjacent layers are found in the 1T 3D *c*-MoS₂, suggesting the atomic thickness of the *c*-MoS₂.

In order to evaluate its electrochemical performance, 3D 1T *c*-MoS₂ was first filtered into a freestanding film as an

electrode. The cross-section SEM image and photograph of the freestanding 3D 1T c-MoS₂ film are shown in [Supplementary Figure S4a,b](#). The electrical conductivity of the 3D 1T c-MoS₂ film derived from the *I*–*V* curve ([Supplementary Figure S4g](#)) is 20.8 S/cm, thus allowing the formation of reasonably thick and porous films without any binding agent. The electrochemical energy storage properties of the filtered 3D 1T c-MoS₂ films were first explored in different aqueous electrolytes, such as Li₂SO₄, Na₂SO₄, K₂SO₄, and MgSO₄. The resulting cyclic voltammogram (CV) profiles in MgSO₄ exhibit a significantly wider stable operating potential and a substantially higher specific capacitance, as indicated in [Supplementary Figure S5a](#). Achieving a stable working potential in electrochemically active materials is a crucial factor to determine the overall working voltage of the full device, in tandem with the output energy density and power density.

For the negative electrode in aqueous electrolytes, the capacitive stable working potential range is mainly determined by the initial hydrogen evolution reaction (HER) potential, which is related to the process of initial proton adsorption onto the catalyst active sites ([Figure 3a](#)). As demonstrated in [Figure 3b,c](#), we systematically evaluated the HER behavior of defective MoS₂ mixed with different cation electrolytes within the computational hydrogen electrode model through density functional theory (DFT) calculations.³⁴ We first employed DFT calculations to determine the hydrogen adsorption free energy (ΔG_{H}) for a series of cations ([Figure 3b](#)). Consistent with previous results,^{35,36} the HER can be catalyzed at the defect sites of the MoS₂ surface with a relatively low overpotential. When additional metal cations are introduced, the adsorbed metal cations are stabilized on the active sites and ΔG_{H} increases significantly relative to the intrinsic 1T deformed basal plane. ΔG_{H} continues to increase with increasing radii of metal cations and ultimately lies around 0.8 eV when the divalent cation, Mg²⁺, resides on the defective basal plane of 1T MoS₂. The result is a surging electronic density that gives rise to the highest overpotential or the largest stable working potential among the different adsorbed cations (Li⁺ < Na⁺ < K⁺ < Mg²⁺), as suggested in the simulation model presented in [Figure 3c](#) and [Supplementary Figure S5d–f](#).

Drawing on DFT insights, we then performed linear sweep voltammograms (LSV). As shown in [Figure 3d](#), polarization curves of 3D 1T c-MoS₂ electrodes measured in sulfate-based electrolytes with different metal cations collectively match well with the predicted impact of adsorbed cations on the capacitive stable working potential. The corresponding overpotential, defined as the potential required to reach current densities of –10 mA/cm², shows that the defective MoS₂ with Mg²⁺ increases the overpotential from –0.58 V in Li₂SO₄ to –0.72 V. Accordingly, the onset potentials for HER are –0.22, –0.26, –0.24, and –0.35 V (*vs* a reversible hydrogen electrode, RHE) for Li₂SO₄, Na₂SO₄, K₂SO₄, and MgSO₄, respectively ([Figure 3d](#), inset). To further verify the impact of cations, we tested monovalent and divalent electrolytes with different anions, *e.g.*, NO₃[–]. It can be seen that the overpotential order for these neutral cation electrolytes within two different types of anions is nearly the same, confirming the cation-dominated effects on the capacitive stable working potential ([Supplementary Figure S5c](#)).

The nearly rectangular nature of the CV curves of 3D 1T c-MoS₂ electrode in 1.0 M MgSO₄ ([Supplementary Figure S5a](#)) indicates capacitive behavior for thick films of 3D 1T c-MoS₂ electrodes. These electrodes exhibited a gravimetric capaci-

tance of 258 F g^{–1} at a scan rate of 1 mV s^{–1} and retained ~64% of their initial capacitance when the scan rate was increased up to 100 mV s^{–1} ([Supplementary Figure S7a](#)). To elucidate the correlation between the 1T phase and the electrochemical properties, we tested MoS₂ electrodes with different ratios of 1T phase. To this end, thick films made of 3D 1T c-MoS₂ were annealed at 100 °C for 1 h under ambient conditions to decrease the concentration of the 1T phase. Deconvolution of the XPS spectra of Mo core-level electron peaks revealed a significantly reduced ratio of the 1T phase (23.2%) among an emerging 2H phase ([Supplementary Figure S6b–d](#)). The local transition in atomic arrangements from octahedral to trigonal prismatic has a profound impact on the macroscopic electrochemical properties. Even mixed with conductive 1T MoS₂ flakes, the 2H phase dominated 3D c-MoS₂ still displayed a specific capacitance of only 143.3 F g^{–1} at 1 mV s^{–1}, which rapidly dropped to 31.9 F g^{–1} when increasing the scan rate to 100 mV s^{–1} ([Supplementary Figure S7a](#)). Meanwhile, we obtained a slightly improved capacitance when incorporating the 3D 1T c-MoS₂ with 1T MoS₂ flakes, giving rise to a slightly improved specific capacitance of 266 F g^{–1} at a low scan rate of 1 mV s^{–1}. However, the specific capacitance drastically decreased to 109 F g^{–1} when the scan rate was increased to 100 mV s^{–1}. Compared with the cross-section and top views of the SEM images ([Supplementary Figure S4a–c](#) for the 3D 1T c-MoS₂ film and [Supplementary Figure S8](#) for the 3D 1T c-MoS₂/ce-1T MoS₂ mixed film), it becomes clear that the dense packing of the MoS₂ flakes and the concomitant less open pores significantly impairs the electrolyte ion transport and subsequently affects the rate performance.

In order to investigate the charge storage contribution and the electrochemical dynamic behavior of the 3D 1T c-MoS₂ electrode, CV curves tested under varied scan rates were systematically analyzed to distinguish the capacitive charge contribution from the diffusion-controlled charge contribution ([Supplementary Figure S9](#)). As shown in [Figure 3e](#), the analysis indicates 72% capacitive charge contribution at a scan rate of 1 mV s^{–1}, which is enhanced to 86% when the scan rate is increased up to 10 mV s^{–1}. Such a high capacitive contribution even at a low scan rate could be another reason for the high rate performance of the 3D 1T c-MoS₂ electrode. In order to fully take advantage of the wide negative potential range of the 3D 1T c-MoS₂ electrode, we used reduced graphene oxide film as the positive electrode to assemble an asymmetric supercapacitor. As demonstrated in the galvanostatic charge and discharge (GCD) ([Figure 3f](#)) and CV ([Figure 3g](#)) curves, the assembled asymmetric supercapacitor can be stably charged/discharged with an output voltage of 1.75 V. The CV curve remains rectangular even when the scan rate is increased to 1000 mV s^{–1}, indicating the high-power capability and good rate performance for the asymmetric device. The great intrinsic electrochemical performance of the 3D 1T c-MoS₂ can guarantee the excellent energy storage capability of the micro-supercapacitor.

We then built MSCs using an inkjet printing technique. In order to achieve high-resolution inkjet-printed MSCs, some important criteria must be taken into account to form very stable jetting: (1) a sufficiently stable ink during jetting; (2) well-matched liquid and solid surface tension/wetting dynamics to establish a spatially uniform material deposition; and (3) particle sizes less than 1/20 that of the nozzle diameter to avoid the jetting nozzle plugging. The choice of solvent is

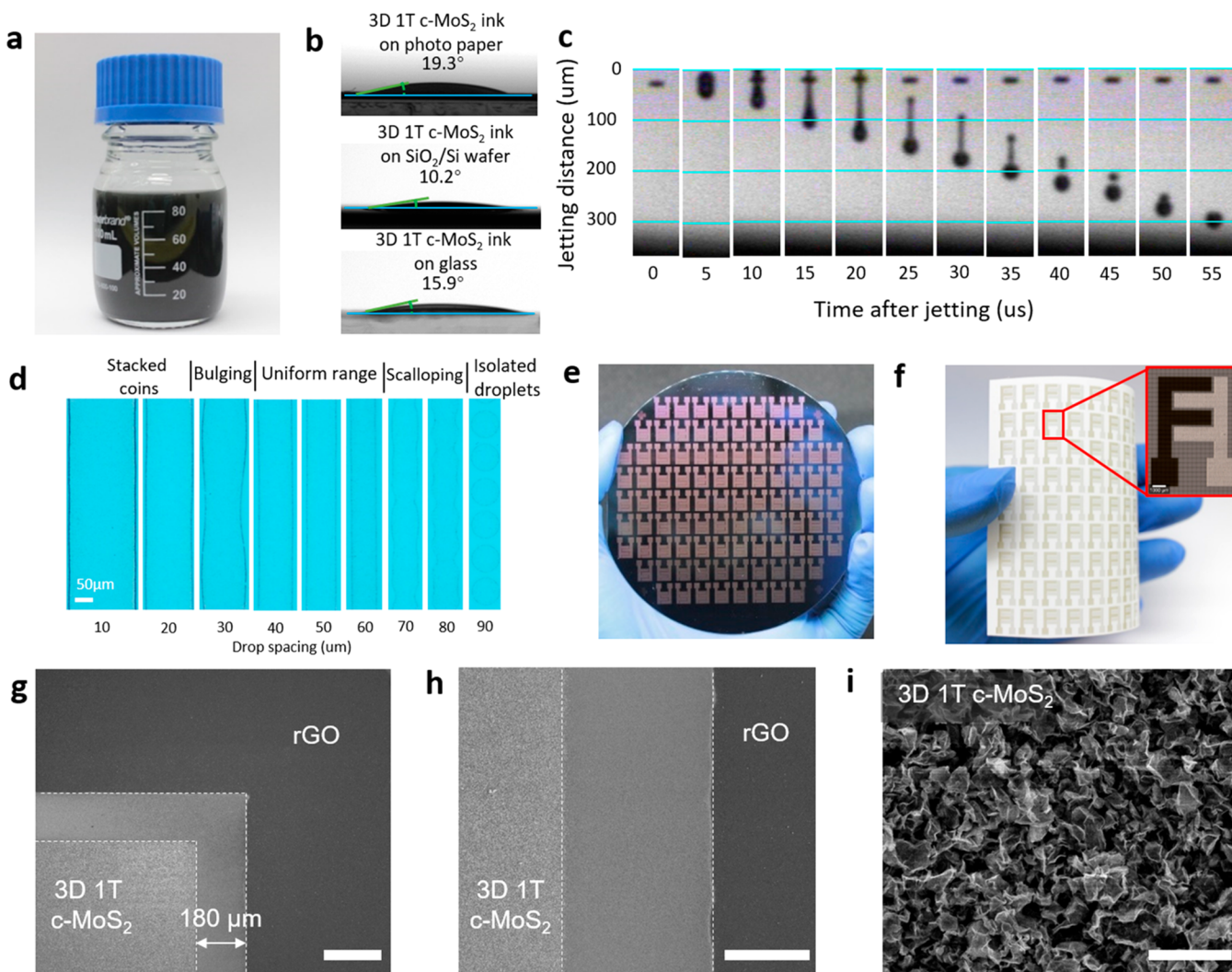


Figure 4. Inkjet printing of asymmetric micro-supercapacitors (AMSCs). (a) Prepared 100 mL of 3D 1T c-MoS₂ ink. (b) Contact angles of 3D 1T c-MoS₂ ink measured on an EPSON paper, a SiO₂/Si substrate, and a glass slide demonstrate the ability of great wetting of 3D 1T c-MoS₂ ink on a wide variety of substrates. (c) Stroboscopic images of inkjet droplets demonstrating the stable ink jetting performance. (d) 3D 1T c-MoS₂ printed on Si/SiO₂ substrates at room temperature illustrates the impact of droplet spacing on forming the line morphology. (e) 96 inkjet-printed interdigital 3D 1T c-MoS₂ MSCs on a 4 in. Si wafer. (f) 96 inkjet-printed 3D 1T c-MoS₂/rGO based AMSCs on flexible photopaper. Inset: Optical microscopic image of a single AMSC. (g, h) SEM image of a printed AMSC with well-defined borders and a straight gap of 180 μm width. (i) SEM image providing a close-up view of the dense packing of 3D 1T c-MoS₂. Scale bars: (g) 400 μm, (h) 100 μm, and (i) 1 μm, respectively.

crucial to achieving a stable dispersion and good substrate wetting. As shown in [Supplementary Figure S10a](#), 3D 1T c-MoS₂ can be dispersed very stably in water, even after 6000 rpm centrifuging. However, the 3D 1T c-MoS₂ dispersion in water exhibited a moderate wetting capability on a majority of substrates, such as a SiO₂/Si substrate with a contact angle of 49.3° ([Supplementary Figure S10e](#)), due to the higher surface tension (γ) of DI-water (72.3 mN m⁻¹) compared with the surface energy of the targeted substrates (Si/SiO₂ or glass ~36 mJ m⁻², PET ~48 mJ m⁻², and polyimide ~44 mJ m⁻²). After switching the dispersing medium to an IPA (surface tension ~23 mN m⁻¹) mixed 2-butanol (surface tension ~22.7 mN m⁻¹) solvent (10 vol % 2-butanol), it indeed did increase the wetting capability to a 10.2° contact angle on a SiO₂/Si substrate. It can be seen that the 3D 1T c-MoS₂ ink with the IPA and 2-butanol mixed solvent remains in a stable dispersion even after scaling up to 100 mL ([Figure 4a](#)), while the well-

formulated solvent combination facilitates the universal yet enhanced wetting characteristics ([Figure 4b](#)).

To demonstrate the utility of the newly formulated 3D 1T c-MoS₂ ink, substrates, including Si/SiO₂, photopaper, glass slides, polyethylene terephthalate (PET), and polyimide films were put to the test. All substrates, regardless of their rigidity, texture, and crystallinity, demonstrated uniform wetting characteristics, as is evident by the markedly decreased contact angles ([Figure 4b](#), [Supplementary Figure S10g,h](#)). Notable too is that 3D 1T c-MoS₂ inks took only a few seconds (7 s for photopaper, 1–3 s for PET, glass slides, and Si/SiO₂) to wet at room temperature ([Supplementary Videos 1–4](#)), leaving behind largely uniform and densely packed 3D 1T c-MoS₂.

The addition of 2-butanol also plays an important role in increasing the dispersibility. As demonstrated in [Supplementary Figure S10c](#), 3D 1T c-MoS₂ ink still exhibited a dark color even after 6000 rpm centrifuging, which indicates significantly increased dispersibility compared to pure IPA solvent. Actually,

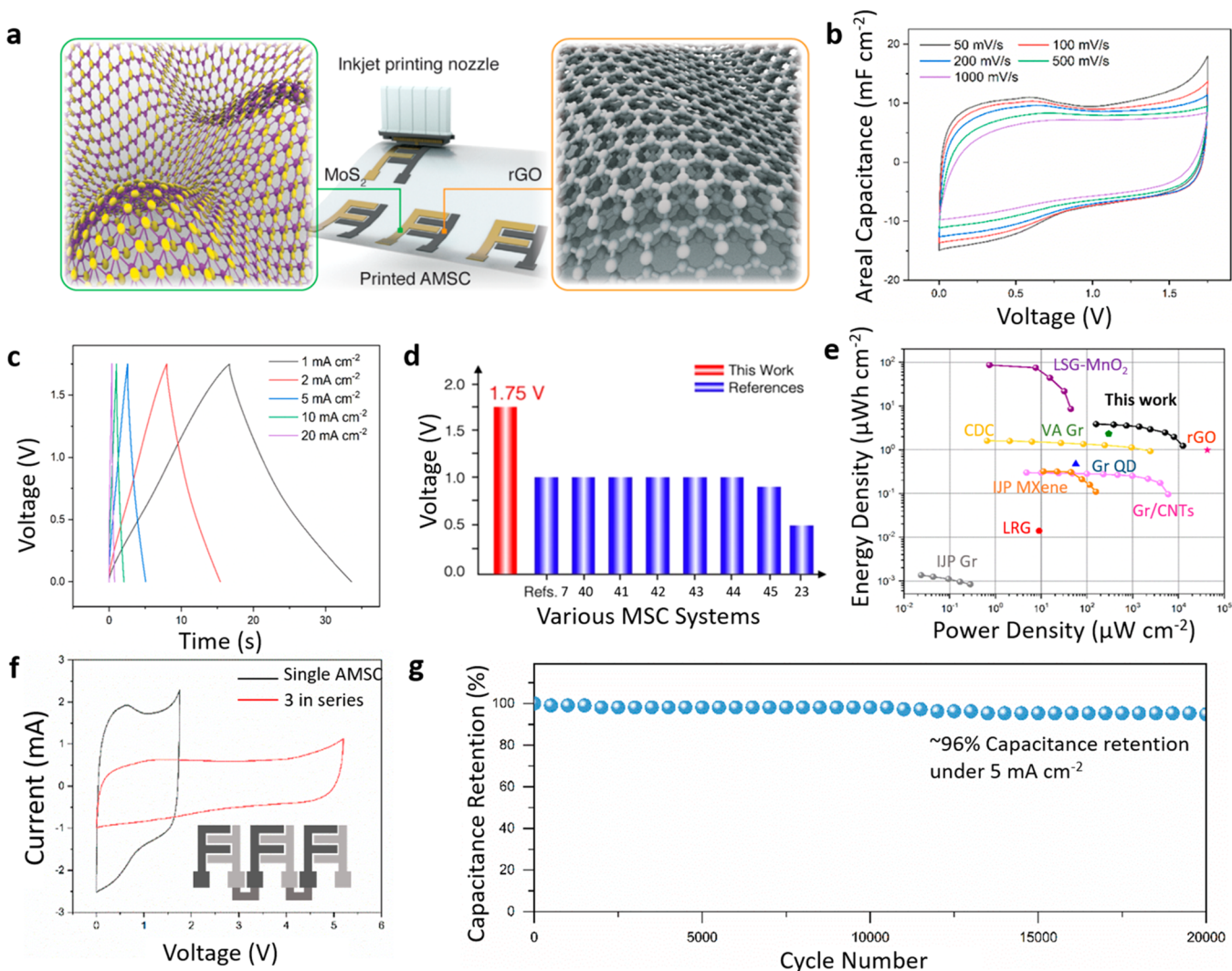


Figure 5. Electrochemical performance of inkjet-printed AMSCs. (a) Schematic depiction of the inkjet-printed asymmetric micro-supercapacitor (AMSC) comprising 3D 1T c-MoS₂ (left) and rGO (right). (b,c) CV and GCD curves of the printed AMSC in 1.0 M MgSO₄ aqueous electrolyte with different scan rates and current densities, respectively. (d) Output voltage of a single AMSC reaches 1.75 V, greatly surpassing previously reported printed MSC devices. The numbers indicate the references. (e) Ragone plot comparison of this work to other state-of-the-art MSC systems, including laser-reduced graphene (LRG),⁴⁰ graphene quantum dots (Gr QD),⁴¹ graphene/carbon nanotube (Gr-CNTs) carpets,⁴² thermally reduced graphene (rGO),⁴³ vertically aligned graphene (VA Gr),⁴⁴ inkjet-printed graphene (IJP Gr),⁴⁵ inkjet-printed MXene (IJP MXene),²³ laser-scribed graphene-MnO₂ (LSG-MnO₂),⁷ and carbon-derived carbon (CDC).⁶ (f) Comparison of the CV curves tested of three connected AMSCs in series with a single AMSC device. (g) Long-term cycling of the printed AMSCs readily reaches 20 000 cycles under 5 mA cm⁻² with ~96% capacitance retention.

for the final ink formation, it only needs 2000 rpm. We attribute the fast drying and associated uniform deposition of 3D 1T c-MoS₂ inks to the low boiling points of the mixed solvent system (IPA ~82.6 °C, 2-butanol ~100 °C) in tandem with the recirculating Marangoni flow that is known to eliminate the unwanted coffee-ring effect during the printing-and-drying processes.^{37,38} Supplementary Figure S10i illustrates the time-dependent contact angle variations right after printing on Si/SiO₂. Initially, the measured contact angles driven by the well-matched liquid and surface wetting characteristics continued to decrease regardless of the dispersing media. As evaporation proceeds toward the end, 3D 1T c-MoS₂ inks dispersed in DI-H₂O and IPA begin to show signs of enrichment and aggregation at the contact edges. We observed that droplets quickly contracted and left behind a series of ring-shaped patterns, thus giving rise to increased contact angles specifically at the final stage of drying. Adding a

cosolvent with a higher boiling point, such as 2-butanol, is found to greatly suppress the coffee-ring effect as a result of the recirculating Marangoni flow that effectively drives 3D 1T c-MoS₂ away from the contact edges and therefore suppresses the coffee-ring effect.

In parallel, the Ohnesorge number, an index of ink jetting stability (explained in Supplementary Note 2),^{21,39} was evaluated to be 10.7. This value falls well within the stable jetting range between 1 and 14. Here, the stable jetted droplets are confirmed by the collated stroboscopic images where the 3D 1T c-MoS₂ ink droplets are well directed and constantly jetted out of the nozzle even for five adjacent jetting nozzles without forming secondary droplets (Figure 4c and Supplementary Figure S11). We also observed very well-ordered printed droplet arrays on Si/SiO₂ substrates (Supplementary Figure S12a). In parallel, the drop spacing is another key parameter to determine the feature size of the printed patterns.

As demonstrated in Figure 4d, when the drop spacing spans between 10 and 20 μm , the printed droplets overlap and then merge into a broad line pattern. When the drop spacing increases to 30 μm , the line pattern becomes bulgy due to the mixture of intermittent droplet overlapping and merging. A further increase in the drop spacing between 40 and 60 μm gives rise to straight- and narrow-line patterns. The printed line patterns develop into a scalloped outline by virtue of the insufficient droplets that are necessary to form the straight edge line when drop spacing further increases to 70 and 80 μm . When the drop spacing is beyond 90 μm , the printed line patterns veer into isolated circles. Thus, drop spacing in the range of 40–60 is the optimized parameter for inkjet printing of 3D 1T c-MoS₂ ink. Here, we inkjet printed 3D 1T c-MoS₂ ink onto various commercially available EPSON photopaper, glass slides, and Si/SiO₂ substrates without prior surface treatments (Supplementary Figure S13b–d).

The accurate deposition of active materials in the inks with well-designed patterns is a critical capability for achieving high-performance MSCs. In this project, we printed 96 AMSCs onto a rigid 4 in. Si/SiO₂ wafer or on flexible EPSON photopaper (Figure 4e,f), with rGO as the positive electrode and 3D 1T c-MoS₂ as the negative electrode. The inset to Figure 4f shows the optical microscopic image revealing the high-resolution printing of two different well-designed interdigitated electrodes. SEM images taken at selected regions of the printed 3D 1T c-MoS₂ (Figure 4i, Supplementary Figure S14a) and rGO wrinkled flakes (Supplementary Figure S15b) exhibited significantly different morphologies where densely packed 3D 1T c-MoS₂ and rGO wrinkled flakes can be clearly distinguished with well-defined straight edges and a gap of 180 μm . Raman mapping in Supplementary Figure S15 and energy-dispersive X-ray (EDX) in Supplementary Figure S16 provide additional details on the spatial distribution of individual active materials.

Figure 5a schematically demonstrates the inkjet-printing fabrication process of 3D 1T c-MoS₂/rGO interdigitated patterns. As demonstrated in the GCD curves of Figure 5c, the printed AMSC can stably charge/discharge with an output voltage of 1.75 V and shows nearly ideal triangular charge/discharge curves even at 20 mA cm⁻². The rate performance of the printed AMSC was evaluated with CV curves under different scan rates. This indicates 70.1% of areal capacitance retention at a high scan rate of 1000 mV s⁻¹ when compared with 9.04 mF cm⁻² at a scan rate of 20 mV s⁻¹. Combined with the largely extended stable working voltage of 1.75 V for a single device, which exceeds most previously reported MSC devices with aqueous electrolytes (Figure 5d), the single 3D 1T c-MoS₂/rGO AMSC device can achieve a high areal energy density of 3.85 $\mu\text{Wh cm}^{-2}$ and a maximum power density of 12.6 mW cm⁻² (at an energy density of 1.23 $\mu\text{Wh cm}^{-2}$). Figure 5e compares the energy density and power density of the printed 3D 1T c-MoS₂/rGO AMSCs with previously reported state-of-the-art MSC devices. Although the energy density alone from the 3D 1T c-MoS₂/rGO AMSCs reported in this work is still below that of the LSG-MnO₂ system,⁷ it is still much better than those of the best-characterized MSCs. Note that since the energy density and power density are proportional to the square of the working voltage, the high output voltage of the printed 3D 1T c-MoS₂/rGO AMSC is in fact critical to achieving high energy storage capability. In parallel, the high working voltage is not only the key descriptor for determining the total energy density and power density but

also an important parameter to drive the electrical devices through connecting in series, thus forming a “power bank” with a specific voltage to meet practical applications. Printed 3D 1T c-MoS₂/rGO AMSCs are demonstrated by connecting three devices together in series (Figure 5f). The tandem 3D 1T c-MoS₂/rGO AMSCs exhibit very good control over the operating voltage window of 5.2 V without any obvious polarization (Supplementary Figure S17a,b). Closely resembling a single 3D 1T c-MoS₂/rGO AMSC, the tandem 3D 1T c-MoS₂/rGO AMSCs can be stably charged/discharged at an output voltage of 5.2 V, while the CV curve remains largely rectangular in shape even when the scan rates are swept from 100 mV s⁻¹ to 2000 mV s⁻¹. Additionally, tandem 3D 1T c-MoS₂/rGO AMSCs are found to exhibit essentially ideal triangular GCD curves along with a straight line in the EIS spectrum, again indicating the uninterrupted capacitive properties with very low internal resistance (Supplementary Figure S17c). The cycling stability is another key parameter for an MSC device. Figure 5g shows the cycling stability of the printed AMSC device, obtained from a GCD test at a current density of 5 mA cm⁻². The AMSC displayed ~96% capacitance retention even after 20 000 continuous cycles.

CONCLUSIONS

In summary, high 1T ultrathin c-MoS₂ was fabricated by a scalable electrospray method and formulated into a binder-free, functional ink for scalable inkjet printing AMSC devices with a high output voltage of 1.75 V in an aqueous electrolyte. The research reported here utilizes only physical transformation of 2D exfoliated layered materials to form a 3D crumpled microstructure. The aggregation-resistant properties of the 1T 3D c-MoS₂ particles endow the electrode film with open space for electrolyte ion transport, leading to good specific capacitance and rate performance. The assembled 3D 1T c-MoS₂/rGO AMSC exhibited a wide stable working voltage of 1.75 V, excellent capacitance retention of 96% over 20 000 cycles, outstanding areal energy density of 3.85 $\mu\text{Wh cm}^{-2}$, and maximum power density of 12.6 mW cm⁻² in a MgSO₄ aqueous electrolyte. The formation of 3D crumpled layered materials could be a general and scalable engineering process for other emerging 2D materials, enabling the creation of functional inks with diverse functional structures. The discovery of 3D crumpled materials that maintain their ultrathin layered structure combined with scalable inkjet printing not only holds tantalizing prospects to realize better micro-supercapacitors but also has wide implications for applications beyond energy storage.

EXPERIMENTAL SECTION

Preparation of 3D 1T c-MoS₂ Solid Inks. The ce-MoS₂ sheets were prepared by a modified Li intercalation method.³⁰ The ce-MoS₂ aqueous dispersion was mixed with DI-H₂O and IPA in a 1:3 volume ratio before proceeding to the electrospray process. The electrospray deposition was performed using a customized setup as illustrated in Supplementary Figure S1a. In brief, the ce-MoS₂ solution (0.25 mg mL⁻¹) was fed into the spinneret (gauge 18 TW needle) by a programmable syringe pump with a flow rate of 5 $\mu\text{L min}^{-1}$. A high electric field (1.35 kV cm⁻¹) was applied through a high-voltage power supply (ES 40P-20W/DAM, Gamma High Voltage Research), and a 5 cm working distance was applied between the tip of the spinneret and the Si wafer collector. The humidity was controlled in the range of ~40–45%. The 3D 1T c-MoS₂ powder can be conveniently collected by gently scraping the deposited powders from the collecting substrates.

Preparation of rGO Dispersion. The rGO dispersion was prepared by the *in situ* liquid phase reduction by hydrazine.⁴⁶

Morphological and Spectroscopic Characterization. The morphology of the 3D 1T c-MoS₂ was imaged using a field emission SEM (FE-SEM, FEI Megellan). EDX spectroscopy mapping of the spatial distribution of each element was acquired by using an EDAX detector fitted on the FE-SEM. HRTEM images were obtained on a spherical aberration coefficient (Cs)-corrected FEI Titan Cube TEM operated with an acceleration voltage of 300 kV. The high-resolution XPS measurements were carried out using a Kratos Axis Ultra DLD spectrometer equipped with a monochromatic Al K_α X-ray source ($h\nu = 1486.6$ eV) operating at 150 W, with a multichannel plate and delay line detector under a vacuum of $\sim 10^{-9}$ mbar. The high-resolution spectra were collected within the limits of spatial resolution at a fixed analyzer pass energy of 20 eV. In order to eliminate the shifts in the HRXPS spectra associated with surface charging effects, the measurements were acquired both with and without electron beam charge compensation. For both cases, no changes were observed in the determined band alignment. The remnant binding energy shifts were referenced to the adventitious carbon (C 1s) signal. Powder X-ray diffraction patterns were recorded using a Bruker D8 Advance instrument with Cu K_α radiation ($\lambda = 0.1542$ nm) operated at 40 kV and 40 mA with a scanning speed at 2 degrees per minute. Optical spectra was taken under a WiTec alpha 300R confocal Raman microscopy system. Gratings of 1800 and 600 mesh mm⁻¹ were selected with a 100× objective (NA = 0.9) from a Carl Zeiss microscope for high-resolution Raman spectra of 3D 1T c-MoS₂ and rGO, respectively. For wavelength calibration, the Si peak at 520 cm⁻¹ on an undoped silicon wafer was used as the reference. Raman spatial mapping was acquired with a grating of 600 mesh mm⁻¹ and a 20× objective.

Calculation and Simulation. The DFT calculations were employed to evaluate the HER overpotential within the computational hydrogen electrode model.³⁴ The prototypical model was constructed using 6 × 6 unit cells. The structural optimizations were performed using the revised Perdew–Burke–Ernzerhof (PRL, 1998, 80, 890) level of DFT, and electrons were described using the plane-augmented wave method⁴⁷ with an energy cutoff of 400 eV. The convergence criteria were set to be 0.001 meV per unit cell. Thereafter, the entropy part of the free energy was evaluated through vibrational frequency calculations. The electron density difference calculations were obtained by calculating the difference between the electron density of the 3D 1T c-MoS₂ with and without the adsorbed metal cations.

Electrochemical Characterization for the Stable Working Potential Ranges. The stable working potential studies of 3D 1T c-MoS₂ were carried out in different neutral cation systems. All the electrochemical measurements were performed on a Bio-Logic VMP3 potentiostat. The filtered 3D 1T c-MoS₂ dispersion mixed with 5 wt % PTFE binder was dropped onto glassy carbon as active electrode for further electrochemical measurements. The LSV for 3D 1T c-MoS₂ in different metal cation systems was carried out in a typical three-electrode system with Pt foil as a counter electrode and a saturated Ag/AgCl electrode as the reference electrode at a scan rate of 5 mV s⁻¹. All the applied potentials were converted to RHE potentials using the equation $E(vs\ RHE) = E(vs\ Ag/AgCl) + 0.197\ V + 0.059\ V \cdot pH$, after IR correction.

3D 1T c-MoS₂ Electrode Electrochemical Test for Charge Storage Capability Evaluation. The as-prepared 3D 1T c-MoS₂ filter papers were cut into 1 cm × 1 cm square pieces. The perfluoroalkoxy (PFA) T-shaped Swagelok tube fitting (PFA-820-3) served as the test body for the three-electrode measurement, graphite foil as the current collector with Pt foil as the counter electrode, and a saturated Ag/AgCl electrode as the reference electrode. For the sandwiched structure asymmetric supercapacitor test, the 3D 1T c-MoS₂ paper and rGO films were assembled as the negative electrode and the positive electrode, respectively, without adding additives, foreign stabilizers, or undergoing further treatments. Then both electrodes were tightly sealed in the test body of the PFA straight Swagelok tube fitting (PFA-820-6).

CV and GCD characterizations were carried out with a potential window of 1.0 V for both aqueous and gel electrolytes. The EIS measurements were performed at an open-circuit potential with a sinusoidal signal over a frequency range from 1 MHz to 10 mHz at an amplitude of 10 mV. The cycle life tests were conducted by GCD measurements.

The areal specific capacitance was calculated from the CV data based on eq 1:

$$C = \frac{\int idV}{SV} (\text{mF cm}^{-2}) \quad (1)$$

where i is the discharge current in the negative CV curve, v is the scan rate, S is the total area of the planar substrate (including the interval spaces between the interdigitated electrodes), and V represents the potential window.

The areal specific energy density and power density were calculated using eqs 2 and 3, respectively:

$$E = \frac{C\Delta V^2}{7200} (\text{mWh cm}^{-2}) \quad (2)$$

$$P = \frac{E3600}{\Delta t} (\text{mW cm}^{-2}) \quad (3)$$

where ΔV is the voltage drop upon discharge in the negative CV curve, Δt is the discharge time, E is the areal energy density (mWh cm⁻²), and P is the areal power density (mW cm⁻²).

Ink Formulation and Printing. Typically, the 3D 1T c-MoS₂ powders were dispersed into mixed solvents composed of 90 vol % IPA and 10 vol % 2-butanol and were stirred for 1 h to afford a homogeneous, stable dispersion with a concentration of 0.5 mg mL⁻¹. Next, 3D 1T c-MoS₂ inks were further sonicated with an ice bath for 1 h. The ink viscosity was characterized via a viscometer (Brookfield, DV3T). The surface tension and contact angles of the 3D 1T c-MoS₂ inks on different substrates were measured by a contact angle analyzer (KRUSS, EasyDrop FM40). The measurements were all conducted at room temperature (~ 20 °C). Meanwhile, rGO inks were prepared by diluting the rGO aqueous dispersions with a hybrid alcohol solvent to a volume ratio of 5 (H₂O):9 (IPA):1 (2-butanol). Before inkjet printing, 3D 1T c-MoS₂ and rGO inks were filtered using 1 and 5 μm syringe filters sequentially to remove unwanted sedimentations. The inkjet printer used in this work is a Fujifilm Dimatix DMP-2850, and the cartridge is a Dimatix DMC-11610 with a 10 pL droplet jetting design. The substrates, including Si/SiO₂ (SiO₂ thickness ~ 150 nm), glass, polyimide film, and PET, were thoroughly cleaned with acetone/ethanol/DI water prior to printing.

Inkjet Printing of AMSCs. The AMSCs were printed according to our previously reported work on rGO-based MSCs.⁸ Specifically, due to the high conductivity, the printed 3D 1T c-MoS₂ and rGO interdigitated patterns directly served as both active electrodes and current collectors. The specific loading mass of 3D 1T c-MoS₂ and rGO are 0.26 and 0.34 mg cm⁻². Meanwhile, silver paste was painted between the square contact area followed by applying conductive copper tape to further decrease the contact resistance. The Kapton tape was used to cover the exposed copper tape to avoid any corrosion by the electrolyte especially when voltage was applied. An aqueous electrolyte of 1.0 M MgSO₄ was then placed on the surface and allowed to infiltrate overnight before electrochemical characterization.

ASSOCIATED CONTENT

Supporting Information

The Supporting Information is available free of charge at <https://pubs.acs.org/doi/10.1021/acsnano.0c02585>.

Supplementary Figures S1–17 showing the electrospray setup, physical characterization (SEM, TEM, XPS), electrochemical characterization of the MoS₂ powder and filtered MoS₂ film along with EDX mapping, Raman

mapping, and electrochemical performance of the printed interdigital AMSC (PDF)

Supplementary video demonstrating the wetting process of 3D 1T c-MoS₂ ink on photopaper (MP4)

Supplementary video demonstrating the wetting process of 3D 1T c-MoS₂ ink on PET (MP4)

Supplementary video demonstrating the wetting process of 3D 1T c-MoS₂ ink on a glass slide (MP4)

Supplementary video demonstrating the wetting process of 3D 1T c-MoS₂ ink on a Si/SiO₂ wafer (MP4)

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Notes

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